

**DIWALIBA POLYTECHNIC, MAHUVA**  
**Mechanical Department**  
**SUBJECT: ENGINEERING PHYSICS (PY0001)**

**CHAPTER 1**  
**SI UNIT and Measurements**

1. The quantity which has the only magnitude is called \_\_\_\_\_
  - a) A scalar quantity
  - b) A vector quantity
  - c) A chemical quantity
  - d) A magnitude quantity
2. The quantity which has the magnitude and direction is called \_\_\_\_\_
  - a) A scalar quantity
  - b) A vector quantity
  - c) A chemical quantity
  - d) A magnitude quantity
3. Force is a vector quantity.
  - a) True
  - b) False
4. Acceleration is a scalar quantity
  - a) True
  - b) False
5. Formula for least count is if,
  - a.  $m$  = Smallest division on main scale
  - b.  $n$  = No. of divisions on Vernier scale
  - a)  $m \times n$
  - b)  $m/n$
  - c)  $m + n$
  - d)  $m - n$
6. S.I. Unit of Power is
  - a. Joule
  - b. watt
  - c. Pascal
  - d. Hertz
7. \_\_\_\_\_ is a Scalar quantity.
  - a) Velocity
  - b) Temperature
  - c) Force
  - d) Acceleration

8. \_\_\_\_\_ is a Vector quantity.
- Velocity
  - Temperature
  - Mass
  - Time
9. 1 Quintal = \_\_\_\_\_ Kilogram.
- 10
  - 1000
  - 0.1
  - 100
10. Formula of Pressure is:
- Force x acceleration
  - Force x time
  - Force/Area
  - Force/ length
11.  $10^9$  is termed as:
- Tera
  - Mega
  - nano
  - Giga
12. \_\_\_\_\_ is not a fundamental quantity.
- Electric Current
  - Pressure
  - Quantity of Matter
  - Mass
13.  $1 \text{ mm}^2 = \text{_____ m}^2$
- $10^{-6}$
  - $10^6$
  - $10^{-7}$
  - $10^7$
14. S.I. Unit of length is:
- Inch
  - Yard
  - metre
  - mile
15. S.I. Unit of surface area is
- $\text{m}^2$
  - $\text{m}^3$
  - $\text{m/s}^2$
  - $\text{m}^2/\text{s}$

16. S.I. Unit of volume is

- a.  $\text{m}^2$
- b.  $\text{m}^3$
- c.  $\text{m/s}^2$
- d.  $\text{m}^2/\text{s}$

17. S.I. Unit of density is

- a.  $\text{Kg/m}^2$
- b.  $\text{m/s}^2$
- c.  $\text{m}^2/\text{s}$
- d.  $\text{kg/m}^3$

18. S.I. Unit of velocity is

- a.  $\text{Kg/m}^2$
- b.  $\text{m/s}$
- c.  $\text{m/s}^2$
- d.  $\text{kg/m}^3$

19. S.I. Unit of force is

- a. Joule
- b. watt
- c. Pascal
- d. newton

20. S.I. Unit of frequency is

- a. Joule
- b. watt
- c. Hertz
- d. Pascal

21. S.I. Unit of pressure is

- a.  $\text{Kg/m}^2$
- b.  $\text{m/s}$
- c.  $\text{N/s}^2$
- d.  $\text{N/m}^2$

22. S.I. Unit of acceleration is

- a.  $\text{Kg/m}^2$
- b.  $\text{m/s}$
- c.  $\text{m/s}^2$
- d.  $\text{kg/m}^3$

23. Formula of momentum is:

- a) mass x acceleration
- b) mass x velocity
- c) Force/Area
- d) Force/ length

24. Formula of work is:
- a) mass x acceleration
  - b) mass x velocity
  - c) Force x Area
  - d) Force x distance
25.  $10^{-9}$  is termed as:
- a. Tera
  - b. Mega
  - c. nano
  - d. Giga
26.  $10^6$  is termed as:
- a. Tera
  - b. Mega
  - c. nano
  - d. Giga
27. In MKS system, unit of length is
- a) inch
  - b) yard
  - c) metre
  - d) mile
28. In MKS system, unit of mass is
- a) gram
  - b) kilogram
  - c) milligram
  - d) ton
29. 1 ton = \_\_\_\_\_ Kilogram.
- a. 10
  - b. 1000
  - c. 0.1
  - d. 100
30. In FPS system, unit of mass is
- a) gram
  - b) kilogram
  - c) milligram
  - d) pound
31. In FPS system, unit of length is
- a) inch
  - b) yard
  - c) foot
  - d) mile

32. In FPS system, unit of time is

- a) hour
- b) minute
- c) millisecond
- d) second

33. In CGS system, unit of mass is

- a) gram
- b) kilogram
- c) milligram
- d) pound

34. In CGS system, unit of length is

- a) metre
- b) centimetre
- c) foot
- d) mile

35. In CGS system, unit of time is

- a) hour
- b) minute
- c) second
- d) millisecond

36. 1 millicurie = \_\_\_\_\_ curie

- a)  $10^{-9}$
- b)  $10^{-6}$
- c)  $10^{-3}$
- d)  $10^3$

37. Water triple point temperature is known as

- a) 1 centigrade
- b) 1 kelvin
- c) 1 Fahrenheit
- d) None of above

38. Significant numbers of 3.531 is

- a) 2
- b) 3
- c) 4
- d) 5

39. Significant numbers of 0.02030 is

- a) 1
- b) 2
- c) 3
- d) 4

40. 6.007 have 2 significant numbers.

- a) True
- b) False

41.  $9.1 \times 10^{-31}$  have 2 significant numbers.

- a) True
- b) False

42. In an experiment to find out Refractive index of glass, observations are 1.36, 1.29, 1.33 then what will be the average refractive index.

- a) 1.33
- b) 1.35
- c) 1.30
- d) 1.29

43. If measured value is closed to true value then accuracy is good.

- a) True
- b) False

44. Least count of Vernier calliper's is

- a. mm
- b. mm
- c. mm
- d. mm

45. Least count of micrometre screw gauge is

- a. mm
- b. mm
- c. mm
- d. mm

46. If Vernier scale's zero mark remain at right side of main scale zero mark then it is called positive error.

- a) True
- b) False

47. If Vernier scale's zero mark remain at left side of main scale zero mark then it is called positive error.

- a) True
- b) False

48. Temperature is a vector quantity.

- a) True
- b) False

49. Velocity is a vector quantity

- a) True
- b) False

50.  $1 \text{ cm}^2 = \underline{\hspace{2cm}} \text{ m}^2$

- a)  $10^{-6}$
- b)  $10^6$
- c)  $10^{-4}$
- d)  $10^4$

### **Chapter 3**

### **General Properties of Matter**

1. External force is applied on body and body undergoes into deflection, as external force removes body regains its original shape this property is called elasticity
  - a) True
  - b) False
  
2. External force is applied on body and body undergoes into deflection, as external force removes body doesn't regain its original shape this property is called elasticity
  - a) True
  - b) False
  
3. Force opposing to deflection of body is called
  - a) Deforming force
  - b) Restoring force
  - c) External force
  - d) None of above
  
4. Body doesn't regain its original size and shape after force removed is called
  - a) Elastic body
  - b) Deformed body
  - c) Plastic body
  - d) None of above
  
5. Body regain its original size and shape after force removed is called
  - a) Elastic body
  - b) Deformed body
  - c) Plastic body
  - d) None of above
  
6. Force applied on body causes deformation is called deforming force
  - a) True
  - b) False
  
7. Force applied on body causes deformation is called restoring force
  - a) True
  - b) False



8. Stress equal to

- a) Force/area
- b) Force x area
- c) Mass/area
- d) Mass x area

9. Stress defined as resistance offered by material to external force per unit area

- a) True
- b) False

10. SI unit of stress is

- a)  $\text{N-s/m}^2$
- b)  $\text{N/m}^3$
- c)  $\text{N/m}^2$
- d)  $\text{N-s/m}^3$

11. Pascal is also a unit of stress

- a) True
- b) False

12. Types of stress is

- a) Longitudinal stress
- b) Volume stress
- c) Shearing stress
- d) All of above

13. If external force is applied on rod and its length is increased then stress generated is called tension

- a) True
- b) False

14. If external force is applied on rod and its length is decreased then stress generated is called compression

- a) True
- b) False

15. Tension and compression both are type of longitudinal stress

- a) True
- b) False

16. External force is applied on solid body causes change in its volume then force applied per unit area of that body is called volume stress.

- a) True
- b) False

17. Stress and pressure both are same.

- a) True
- b) False

18. According to Hooke's law

- a) Stress is inversely proportional to strain
- b) Stress is reciprocal of strain
- c) Stress is directly proportional to strain
- d) None of above

19. Young's modulus equal to

- a) Strain/stress
- b)  $1/\text{Stress}$
- c) Stress/strain
- d)  $1/\text{strain}$

20. Bulk modulus is equal to

- a) Stress/strain
- b) Longitudinal stress/longitudinal strain
- c) Shearing stress/shearing strain
- d) Volume stress/volume strain

21. Modulus of rigidity equal to

- a) Stress/strain
- b) Longitudinal stress/longitudinal strain
- c) Shearing stress/shearing strain
- d) Volume stress/volume strain

22. Poisson's ratio equal to

- a) Stress/strain
- b) Lateral strain/longitudinal strain
- c) shearing strain /Shearing stress
- d) Volume stress/ longitudinal strain

23. Strain equal to

- a) Change in length/original length
- b) original length /Change in length
- c) both (A) & (B)
- d) None of above

24. Volumetric Strain equal to

- a) Change in length/original length
- b) original length /Change in length
- c) both (A) & (B)
- d) Change in volume/original volume

25. Lateral Strain equal to

- a) Change in length/original length
- b) Change in diameter /original diameter
- c) both (A) & (B)
- d) Change in volume/original volume

26. Equation of young modulus from experiment is

- a)  $\pi r^2 \Delta l / mgl$
- b)  $m \pi r^2 / gl \Delta l$
- c)  $mgl / \pi r^2 \Delta l$
- d)  $m \Delta l / gl \pi r^2$

27. Equation for deflection of beam having weight (W) in the middle is equal to

- a)  $WL^3 / 4bd^3 y$
- b)  $4bd^3 y / WL^3$
- c)  $WL^3 y / 4bd^3$
- d)  $4bd^3 / WL^3 y$

28. Height of mountains are limited because of its

- a) Plasticity
- b) Elasticity
- c) Elastic limit
- d) Plastic limit

29. SI unit of surface tension is

- a) N-m
- b) N/m
- c) m/N
- d) None of above

30. Types of molecular force is

- a) Cohesive force
- b) Adhesive force
- c) Both (A) & (B)
- d) None of above

31. Force exerted between same molecules is known as cohesive force

- a) True
- b) False

32. Force exerted between different molecules is known as Adhesive force

- a) True
- b) False

33. Molecular force exerted between molecules up to certain distance, this distance is called

- a) Molecular distance
- b) Molecular range
- c) Sphere of influence
- d) None of above

34. Surface energy per unit area of free surface of stationary liquid is called surface tension of that liquid

- a) True
- b) False

35. CGS unit of surface tension is

- a) Erg/cm<sup>2</sup>
- b) N/m
- c) m/N
- d) None of above

36. If angle of contact is less than  $90^\circ$ , then

- a) Liquid wets surface
- b) Liquid doesn't wet surface
- c) No effect on surface
- d) None of above

37. If angle of contact is greater than  $90^\circ$ , then

- a) Liquid wets surface
- b) Liquid doesn't wet surface
- c) No effect on surface
- d) None of above

38. Value of angle of contact for water is

- a)  $90^\circ$
- b)  $0^\circ$
- c)  $17^\circ$
- d)  $148^\circ$

39. Value of angle of contact for alcohol is

- a)  $90^\circ$
- b)  $0^\circ$
- c)  $17^\circ$
- d)  $148^\circ$

40. Value of angle of contact for mercury is

- a)  $90^\circ$
- b)  $0^\circ$
- c)  $17^\circ$
- d)  $148^\circ$

41. Value of angle of contact for turpentine is

- a)  $90^\circ$
- b)  $0^\circ$
- c)  $17^\circ$
- d)  $148^\circ$

42. Value of angle of contact for paraffin is

- a)  $107^\circ$
- b)  $90^\circ$
- c)  $0^\circ$
- d)  $148^\circ$

43. If angle of contact is less than  $90^\circ$ , then

- a) Shape of free surface is concave
- b) Shape of free surface is convex
- c) Both (A) & (B)
- d) None of above

44. If angle of contact is greater than  $90^\circ$ , then

- a) Shape of free surface is concave
- b) Shape of free surface is convex
- c) Both (A) & (B)
- d) None of above

45. Formula for surface tension is

- a)  $\frac{rhdg}{2 \cos\theta}$
- b)  $\frac{2\cos\theta}{rhdg}$
- c)  $\frac{rhd}{2g \cos\theta}$
- d)  $\frac{2g \cos\theta}{rhd}$

46. Viscosity of water is more than oil

- a) True
- b) False

47. Viscosity of honey is greater than water

- a) True
- b) False

48. SI unit of viscosity is

- a)  $\text{N-s/m}^2$
- b) centistoke
- c)  $\text{dyne-s/cm}^2$
- d) poise

49. Reynold's number is less than 2000, then

- a) Flow is transient
- b) Flow is turbulent
- c) Flow is laminar
- d) None of above

50. Reynold's number is greater than 3000, then

- a) Flow is transient
- b) Flow is turbulent
- c) Flow is laminar
- d) None of above

## **Chapter 5**

### **Semiconductor & Nanotechnology**

1. What does the conductivity of metals depend upon?
  - a) The nature of the material
  - b) Number of free electrons
  - c) Resistance of the metal
  - d) Number of electrons
  
2. What happens to the free electrons when an electric field is applied?
  - a. They move randomly and collide with each other
  - b. They move in the direction of the field
  - c. They remain stable
  - d. They move in the direction opposite to that of the field
  
3. What are the charge carriers in semiconductors?
  - a) Electrons and holes
  - b) Electrons
  - c) Holes
  - d) Charges
  
4. How are charge carriers produced in intrinsic semiconductors?
  - a. By pure atoms
  - b. By electrons
  - c. By impure atoms
  - d. By holes
  
5. What type of material is obtained when an intrinsic semiconductor is doped with pentavalent impurity?
  - a) N-type semiconductor
  - b) Extrinsic semiconductor
  - c) P-type semiconductor
  - d) Insulator
  
6. P-type semiconductor is obtained through doping \_\_\_\_\_ impurity in an intrinsic semiconductor
  - a) pentavalent
  - b) tetravalent
  - c) trivalent
  - d) hexavalent



7. N-type semiconductor is obtained through doping \_\_\_\_\_ impurity in an intrinsic semiconductor
- a) tetravalent
  - b) trivalent
  - c) hexavalent
  - d) pentavalent
8. What type of material is obtained when an intrinsic semiconductor is doped with trivalent impurity?
- a) Extrinsic semiconductor
  - b) Insulator
  - c) N-type semiconductor
  - d) P-type semiconductor
9. When does a normal conductor become a superconductor?
- a) At normal temperature
  - b) At Curie temperature
  - c) At critical temperature
  - d) Never
10. Meissner effect occurs in superconductors due to which of the following properties?
- a) Diamagnetic property
  - b) Magnetic property
  - c) Paramagnetic property
  - d) Ferromagnetic property
11. Superconductors can be used as a memory or storage elements in computers.
- a. True
  - b. False
12. What are the major charge carriers in P-type semiconductors?
- a) Electrons
  - b) Protons
  - c) Holes
  - d) Photons
13. What are the major charge carriers in N-type semiconductors?
- a) Protons
  - b) Holes
  - c) Photons
  - d) Free Electrons

14. Which type of impurity generated in P-type semiconductor?
- a) Conductor
  - b) Acceptor
  - c) Donor
  - d) Valence
15. Which type of impurity generated in N-type semiconductor?
- a) Conductor
  - b) Acceptor
  - c) Donor
  - d) Valence
16. The concentration of doping is kept below \_\_\_\_\_
- a) 1 %
  - b) 5 %
  - c) 10 %
  - d) 50 %
17. In N-Type semiconductors, which extra energy level is added?
- a. Conduction level
  - b. Donor Energy Level
  - c. Acceptor energy level
  - d. Valence level
18. Which of the following can be used to create a P-Type Semiconductor?
- a) P
  - b) Sb
  - c) Ga
  - d) As
19. Which one of the following is not an intrinsic semiconductor?
- a) Carbon
  - b) Silicon
  - c) Germanium
  - d) Lead
20. P-Type semiconductor has a lower electrical conductivity than N-Type semiconductor.
- a) True
  - b) False
21. Holes are the majority carries in Intrinsic Semiconductors.
- a) True
  - b) False

22. In a P-N Junction, the depletion region is reduced when \_\_\_\_\_
- a) P side is connected to the negative side of the terminal
  - b) P side is connected to the positive side of the terminal
  - c) N side is connected to the positive side of the terminal
  - d) Never reduced
23. The voltage at which forward bias current increases rapidly is called as \_\_\_\_\_
- a) Breakdown Voltage
  - b) Forward Voltage
  - c) Knee Voltage
  - d) Voltage barrier
24. The resistance of the semiconductor decreases in forward biased.
- a) True
  - b) False
25. The current produced in reverse-bias is called as \_\_\_\_\_
- a) Reverse Current
  - b) Breakdown Current
  - c) Negative Current
  - d) Leakage Current
26. The leakage current is measured in \_\_\_\_\_
- a) A
  - b) mA
  - c)  $\mu\text{A}$
  - d) nA
27. CVD stands for \_\_\_\_\_
- a) Carbon vapour density
  - b) Chemical vapour density
  - c) Chemical vapour deposition
  - d) Carbon vapour deposition
28. CNTs stands for \_\_\_\_\_
- a) Carbon Nanotubes
  - b) Carbon Nanotechnology
  - c) Carbon Nanoscience and technology
  - d) Carbon Nine Technology
29. The carbon tubes have high conductivity.
- a) True
  - b) False

30. Which property of Nanomaterials make them suitable to be used for elimination of pollutants?

- a) High purity
- b) Better thermal conductivity
- c) Enhanced chemical activity
- d) Small size

31. Which nanomaterial is used for cutting tools?

- a) Fullerene
- b) Aerogel
- c) Tungsten Carbide
- d) Gold

32. Valence electrons situated in

- a) Valence band
- b) Conduction band
- c) Forbidden gap
- d) None of above

33. Free electrons are situated in

- a) Valence band
- b) Conduction band
- c) Forbidden gap
- d) None of above

34. For insulators, conduction band is

- a) Fully filled with free electrons
- b) Partially filled with free electrons
- c) Empty
- d) None of above

35. For conductors, conduction band is

- a) Fully filled with free electrons
- b) Partially filled with free electrons
- c) Empty
- d) None of above

36. For conductors, valence band is

- a) Partially filled with free electrons at 0 K
- b) Fully filled with free electrons at 0 K
- c) Empty
- d) None of above

37. For insulators, valence band is

- a) Partially filled with free electrons at 0 K
- b) Fully filled with free electrons at 0 K
- c) Empty
- d) None of above

38. For semiconductors, valence band is

- a) Empty
- b) Partially filled with free electrons at 0 K
- c) Fully filled with free electrons at 0 K
- d) None of above

39. Electrical resistivity of conductors is equal to

- a)  $10^{-6} \Omega\text{m}$
- b)  $10^{-4} \Omega\text{m}$  to  $10^3 \Omega\text{m}$
- c)  $10^3 \Omega\text{m}$  to  $10^{27} \Omega\text{m}$
- d)  $10^{-9} \Omega\text{m}$  to  $10^{-6} \Omega\text{m}$

40. Electrical resistivity of semiconductor is equal to

- a)  $10^{-6} \Omega\text{m}$
- b)  $10^{-4} \Omega\text{m}$  to  $10^3 \Omega\text{m}$
- c)  $10^3 \Omega\text{m}$  to  $10^{27} \Omega\text{m}$
- d)  $10^{-9} \Omega\text{m}$  to  $10^{-6} \Omega\text{m}$

41. Electrical resistivity of insulator is equal to

- a)  $10^{-6} \Omega\text{m}$
- b)  $10^{-4} \Omega\text{m}$  to  $10^3 \Omega\text{m}$
- c)  $10^3 \Omega\text{m}$  to  $10^{27} \Omega\text{m}$
- d)  $10^{-9} \Omega\text{m}$  to  $10^{-6} \Omega\text{m}$

42. Energy gap for conductor is equal to

- a) 1.21 eV
- b) 5 eV
- c) 1 eV
- d) 0.785 eV

43. Energy gap for insulator is equal or greater than to

- a) 1.21 eV
- b) 5 eV
- c) 1 eV
- d) 0.785 eV

44. Energy gap for germanium at 0 K is equal to

- a) 1.21 eV
- b) 5 eV
- c) 1 eV
- d) 0.785 eV

45. Energy gap for silicon at 0 K is equal to

- a) 1.21 eV
- b) 5 eV
- c) 1 eV
- d) 0.785 eV

46. Process of adding impurities in intrinsic semiconductor is called doping

- a) True
- b) False

47. Value of critical temperature of mercury is

- a) 1.20 K
- b) 4.22 K
- c) 7.18 K
- d) 9.46 K

48. Temperature at which specimen converted into superconductor is known as critical temperature.

- a) True
- b) False

49. Value of critical temperature of aluminium is

- a) 1.20 K
- b) 4.22 K
- c) 7.18 K
- d) 9.46 K

50. Flux density in superconductor is equal to

- a) Maximum
- b) Minimum
- c) Zero
- d) None of above